## NSN 5961-01-432-7241

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-432-7241 **Inclosure Material:** Glass and metal **Overall Length:** 1.550 inches **Overall Height:** 0.425 inches **Overall Width:** 1.000 inches **Mounting Facility Quantity: Component Name And Quantity:** 6 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 100.0 reverse breakdown voltage, dc all semiconductor and 100.0 working peak reverse voltage all semiconductor **Current Rating Per Characteristic:** 250.00 amperes peak forward surge current nanoamperes all semiconductor **Terminal Type And Quantity:** 5 turret Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: